Diode Semiconductor Device - Page 1 of 1



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| Inclosure Material:  |
|--|
| Glass and plastic  |
| Overall Length:  |
| 0.375 inches   |
| Terminal Length:   |
| 1.000 inches   |
| Overall Diameter:  |
| 0.210 inches   |
| Joint Electronic Device Engineering Council/jedec/case Outline Designation:                      |
| Do-27  |
| Mounting Method:   |
| Terminal   |
| Semiconductor Material:  |
| Silicon  |
| Voltage Rating In Volts Per Characteristic:  |
| 400.0 repetitive peak reverse voltage, peak total value and 400.0 reverse voltage, instantaneous |
| Current Rating Per Characteristic:   |
| 3.00 amperes average forward current averaged over a full 60-hz cycle                            |
| Maximum Operating Tempurature Per Measurement Point:   |
| 175.0 degrees celsius ambient air  |
| Terminal Type And Quantity:  |
| 2 uninsulated wire lead  |
| Shelf Life:  |
| N/a  |
| Unit Of Measure:   |
|  |
| Demilitarization:  |
| No   |
| Fiig:  |
|  |

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